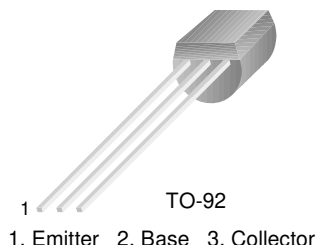


KSC1187

KSC1187

TV 1st, 2nd Picture IF Amplifier (Forward AGC)

- High Current Gain Bandwidth Product : $f_T=700\text{MHz}$
- High Power Gain : $G_{PE}=24\text{dB}$ (TYP.) at $f=45\text{MHz}$



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	30	V
V_{CEO}	Collector-Emitter Voltage	20	V
V_{EBO}	Emitter-Base Voltage	4	V
I_C	Collector Current	30	mA
P_C	Collector Power Dissipation	250	mW
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C=10\mu\text{A}, I_E=0$	30			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C=5\text{mA}, I_B=0$	25			V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E=10\mu\text{A}, I_C=0$	4			V
I_{CBO}	Collector Cut-off Current	$V_{CB}=20\text{V}, I_E=0$			0.1	μA
h_{FE}	DC Current Gain	$V_{CE}=10\text{V}, I_C=2\text{mA}$	40		240	
f_T	Current Gain Bandwidth Product	$V_{CE}=10\text{V}, I_C=3\text{mA}$	400	700		MHz
C_{RE}	Reverse Transfer Capacitance	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$		0.6		pF
G_{PE}	Power Gain	$V_{CE}=10\text{V}, I_C=3\text{mA}$ $f=45\text{MHz}$	20	24		dB
V_{AGC}	AGC Voltage	$G_R=30\text{dB}, f=45\text{MHz}$	4.4	5.2	6.0	V

h_{FE} Classification

Classification	R	O	Y
h_{FE}	40 ~ 80	70 ~ 140	120 ~ 240

Typical Characteristics

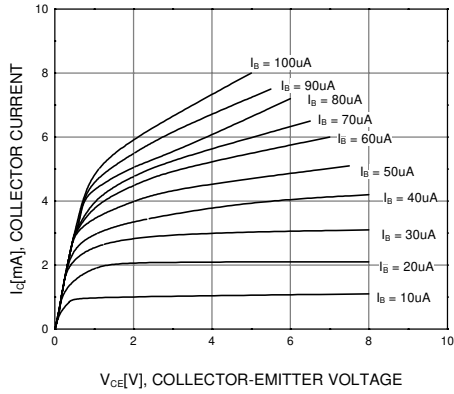


Figure 1. Static Characteristic

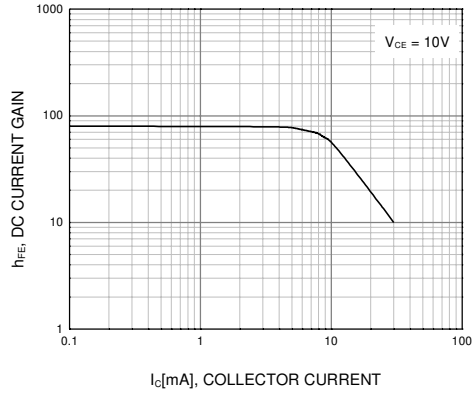


Figure 2. DC current Gain

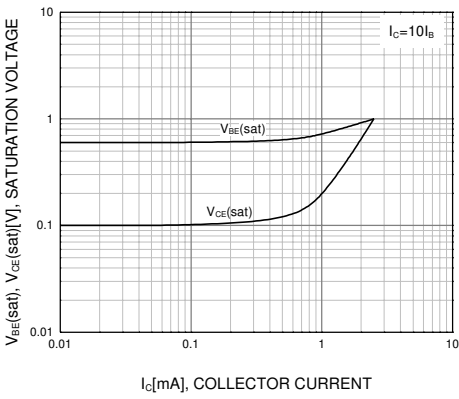


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

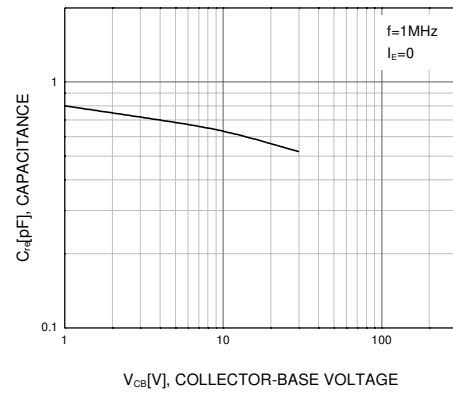


Figure 4. Reverse Capacitance

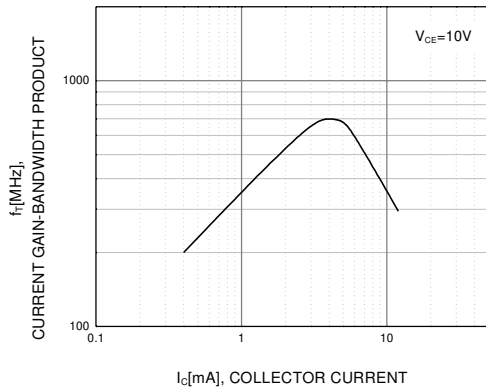
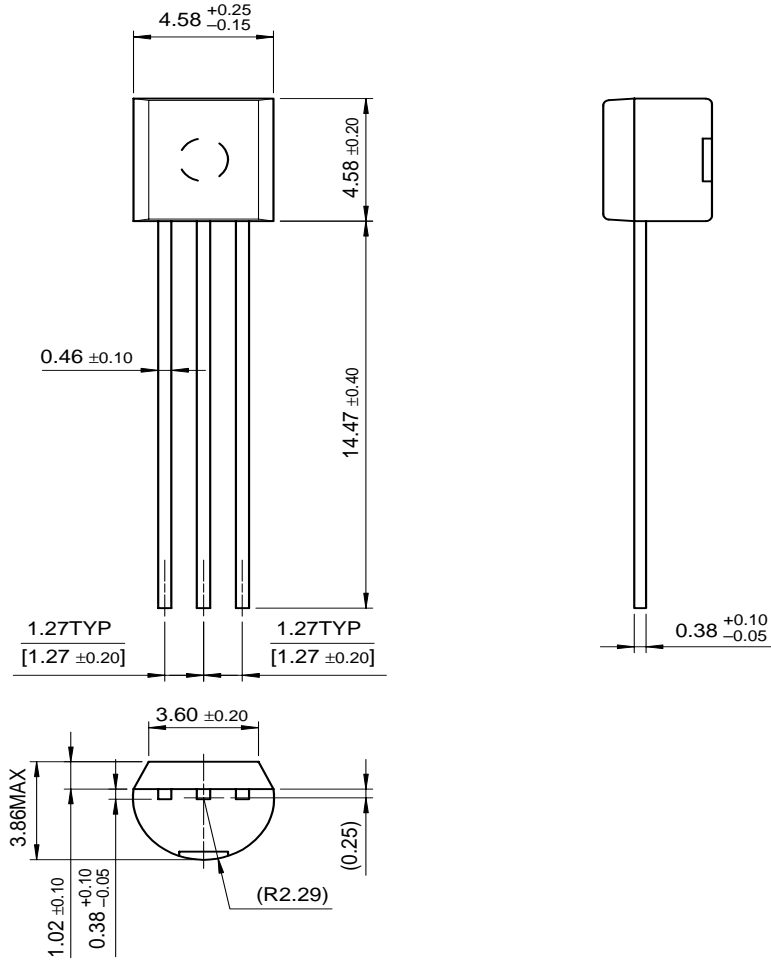


Figure 5. Current Gain Bandwidth Product

Package Dimensions

TO-92



Dimensions in Millimeters

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